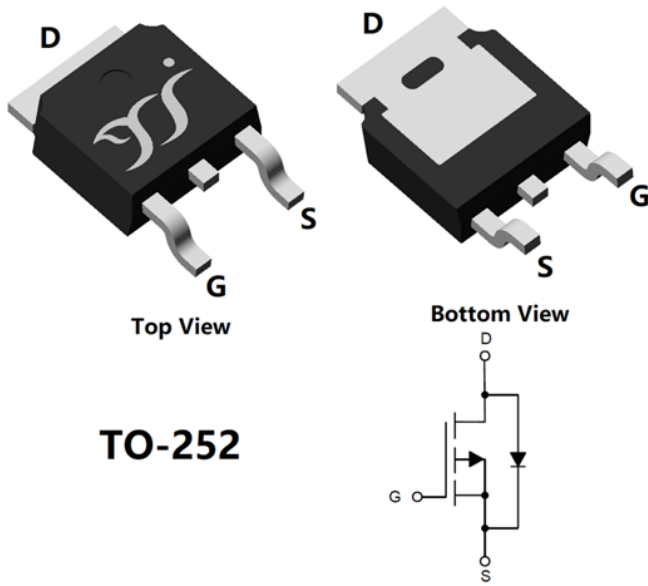




P-Channel Enhancement Mode Field Effect Transistor



Product Summary

• V_{DS}	-60V
• I_D	-19A
• $R_{DS(ON)}$ (at $V_{GS}=-10V$)	<55m Ω
• 100% EAS Tested	
• 100% ∇V_{DS} Tested	

General Description

- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free
- Part no. with suffix "Q" means AEC-Q101 qualified

Applications

- Power management
- Load Switch

Limiting Values

Parameter	Conditions		Symbol	Min	Max	Unit
Drain-source Voltage			V _{DS}	-	-60	V
Gate-source Voltage (Note 4)			V _{GS}	-20	20	
Continuous Drain Current (Note 1,2)	Steady-State	T _A =25°C,V _{GS} =-10V	I _D	-	-5	A
		T _A =100°C,V _{GS} =-10V		-	-3.5	
Continuous Drain Current (Note 1,3)	Steady-State	T _C =25°C,V _{GS} =-10V,Chip limitation		-	-19	
		T _C =100°C,V _{GS} =-10V		-	-13	
Pulsed Drain Current	T _C =25°C,t _p ≤10μs		I _{DM}	-	-69	
Maximum Body-Diode Continuous Current	T _C =25°C		I _S		-19	
Avalanche Energy (non-repetitive)	T _J =25°C,V _G =-10V,R _G =25Ω,L=0.5mH,I _{AS} =-14A		EAS	-	49	mJ
Total Power Dissipation (Note 1,2)	Steady-State	T _A =25°C	P _D	-	2.9	W
		T _A =100°C		-	1.5	
Total Power Dissipation (Note 1,3)	Steady-State	T _C =25°C		-	43	
		T _C =100°C		-	21	
Junction and Storage Temperature Range			T _J ,T _{STG}	-55	175	°C

Thermal Resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient (Note 2)	Steady-State	$R_{\theta JA}$	-	51	$^{\circ}C/W$
Thermal Resistance Junction-to-Case	Steady-State	$R_{\theta JC}$	-	3.5	

Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJD055P06AHQ	F1/F2	YJD055P06A	2500	/	25000	13" reel



YJD055P06AHQ

■ Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A, T_j=25^{\circ}C$	-60	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-60V, V_{GS}=0V, T_j=25^{\circ}C$	-	-	-1	μA
		$V_{DS}=-60V, V_{GS}=0V, T_j=175^{\circ}C$	-	-	-100	
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V, T_j=25^{\circ}C$	-	-	± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A, T_j=25^{\circ}C$	-1.2	-2	-2.8	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-10A, T_j=25^{\circ}C$	-	41	55	m Ω
Diode Forward Voltage	V_{SD}	$I_S=-10A, V_{GS}=0V, T_j=25^{\circ}C$	-	-0.87	-1.2	V
Gate Resistance	R_G	$f=1MHz, T_j=25^{\circ}C$	-	8.4	-	Ω
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{DS}=-30V, V_{GS}=0V, f=1MHz, T_j=25^{\circ}C$	-	1463	-	pF
Output Capacitance	C_{oss}		-	91	-	
Reverse Transfer Capacitance	C_{rss}		-	82	-	
Switching Parameters						
Total Gate Charge	Q_g	$V_{GS}=-10V, V_{DS}=-30V, I_D=-10A, T_j=25^{\circ}C$	-	32.6	-	nC
Gate-Source Charge	Q_{gs}		-	5.4	-	
Gate-Drain Charge	Q_{gd}		-	5.7	-	
Reverse Recovery Charge	Q_{rr}	$I_F=-10A, di/dt=100A/\mu s, V_{GS}=0V, V_R=-30V, T_j=25^{\circ}C$	-	33	-	nC
Reverse Recovery Time	t_{rr}		-	25	-	ns
Turn-on Delay Time	$t_{D(on)}$	$V_{GS}=-10V, V_{DS}=-30V, I_D=-10A, R_{GEN}=3\Omega, T_j=25^{\circ}C$	-	9	-	ns
Turn-on Rise Time	t_r		-	12	-	
Turn-off Delay Time	$t_{D(off)}$		-	41	-	
Turn-off Fall Time	t_f		-	19	-	

Note:

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
2. The value of $R_{\theta JA}$ is measured with the device mounted on the 40mm*40mm*1.1mm single layer FR-4 PCB board with 1 in² pad of 2oz. Copper, in the still air environment with $T_A=25^\circ C$. The maximum allowed junction temperature of $175^\circ C$. The value in any given application depends on the user's specific board design.
3. Thermal resistance from junction to soldering point (on the exposed drain pad).
4. $V_{GS}=-20V/+10V$ according AEC-Q101 at $T_j=175^\circ C$.



■ Typical Electrical and Thermal Characteristics Diagrams

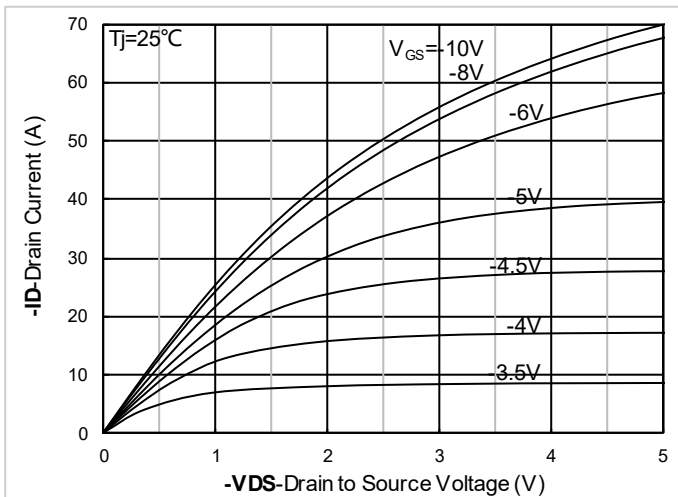


Figure 1. Output Characteristics; typical values

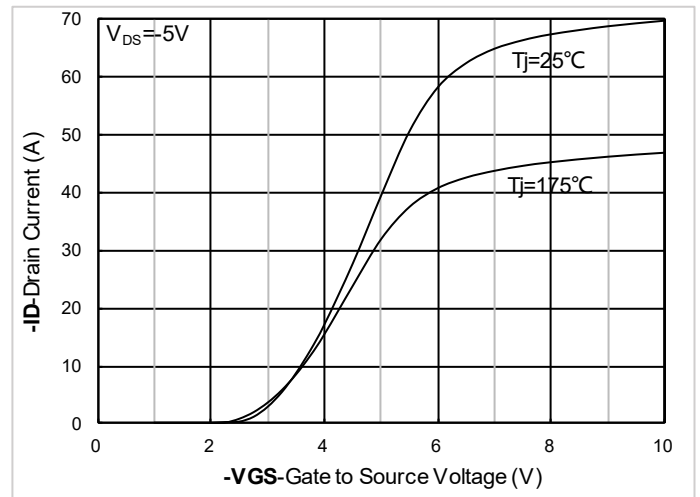


Figure 2. Transfer Characteristics; typical values

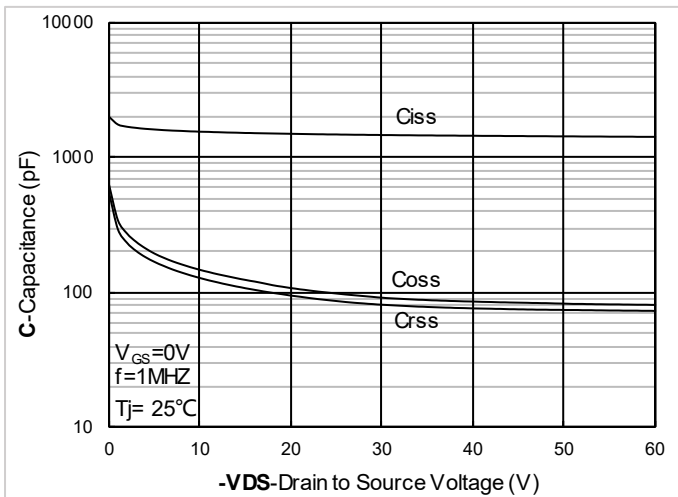


Figure 3. Capacitance Characteristics; typical values

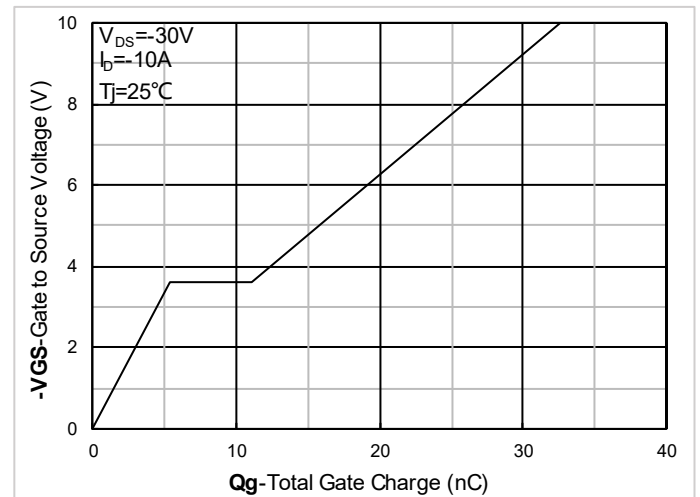


Figure 4. Gate Charge; typical values

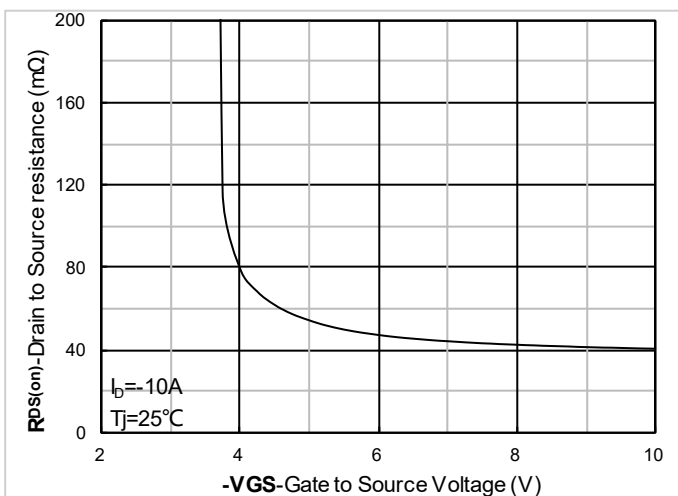


Figure 5. On-Resistance vs. Gate to Source Voltage; typical values

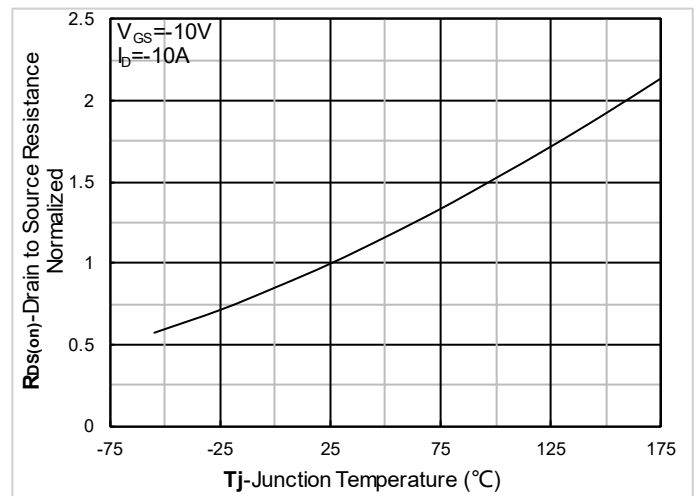


Figure 6. Normalized On-Resistance

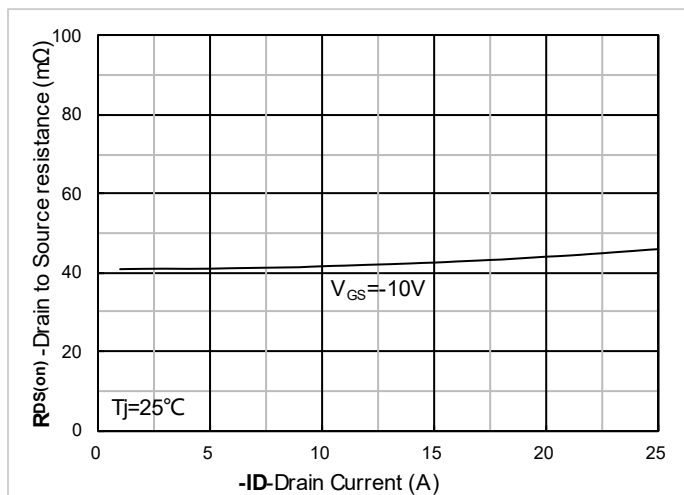


Figure 7. RDS(on) vs. Drain Current; typical values

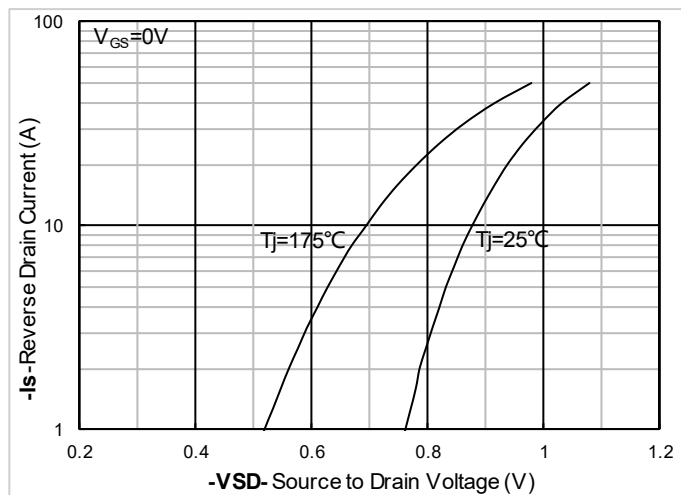


Figure 8. Forward characteristics of reverse diode; typical values

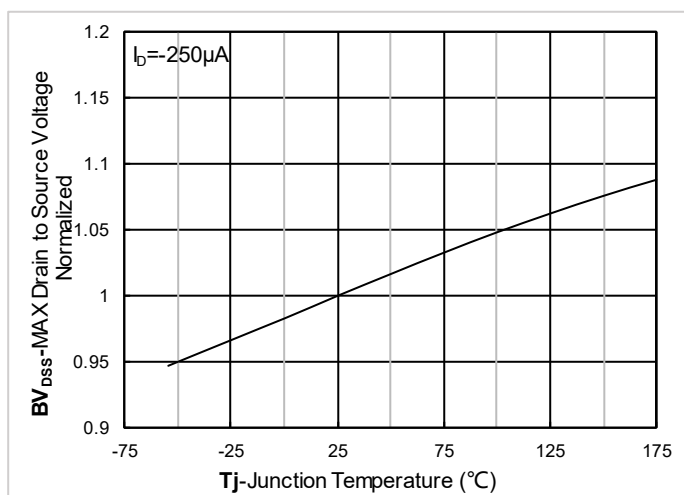


Figure 9. Normalized breakdown voltage

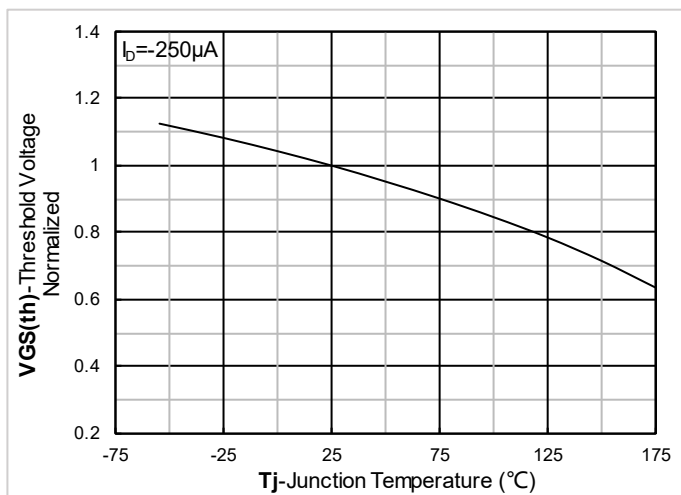


Figure 10. Normalized Threshold voltage

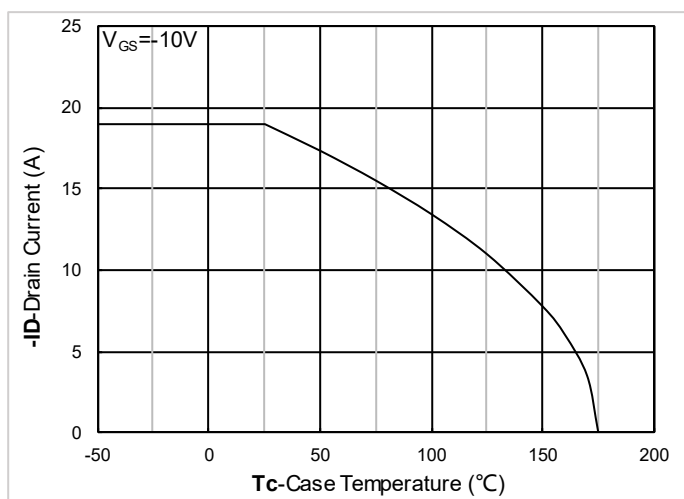


Figure 11. Current dissipation

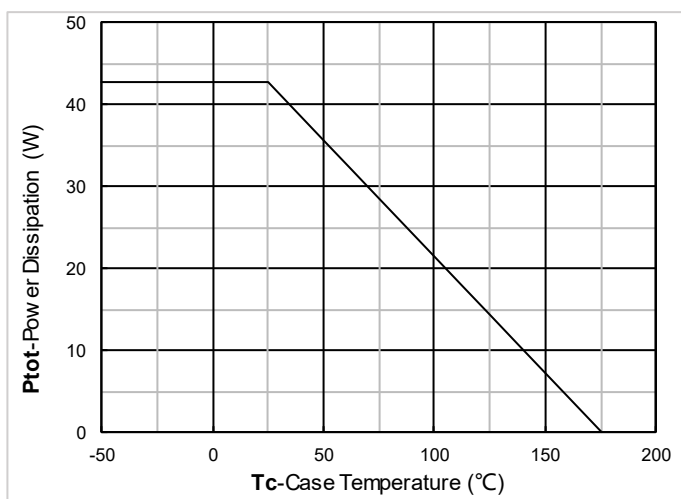


Figure 12. Power dissipation

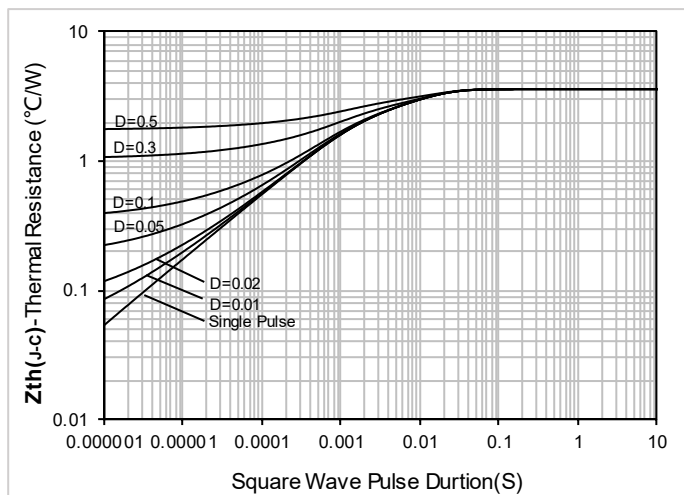


Figure 13. Maximum Transient Thermal Impedance

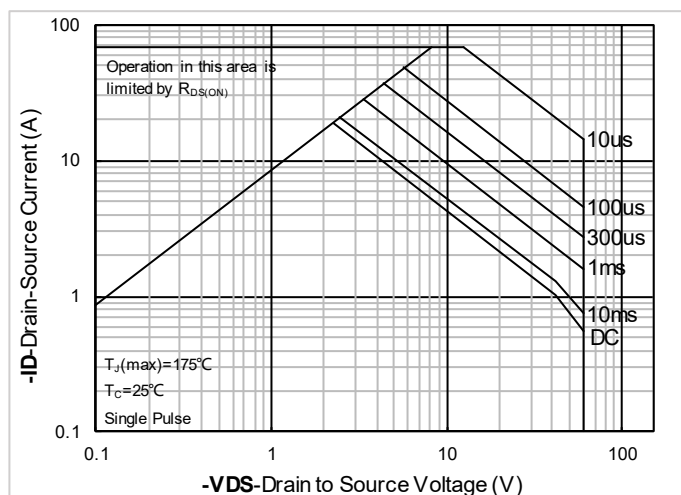
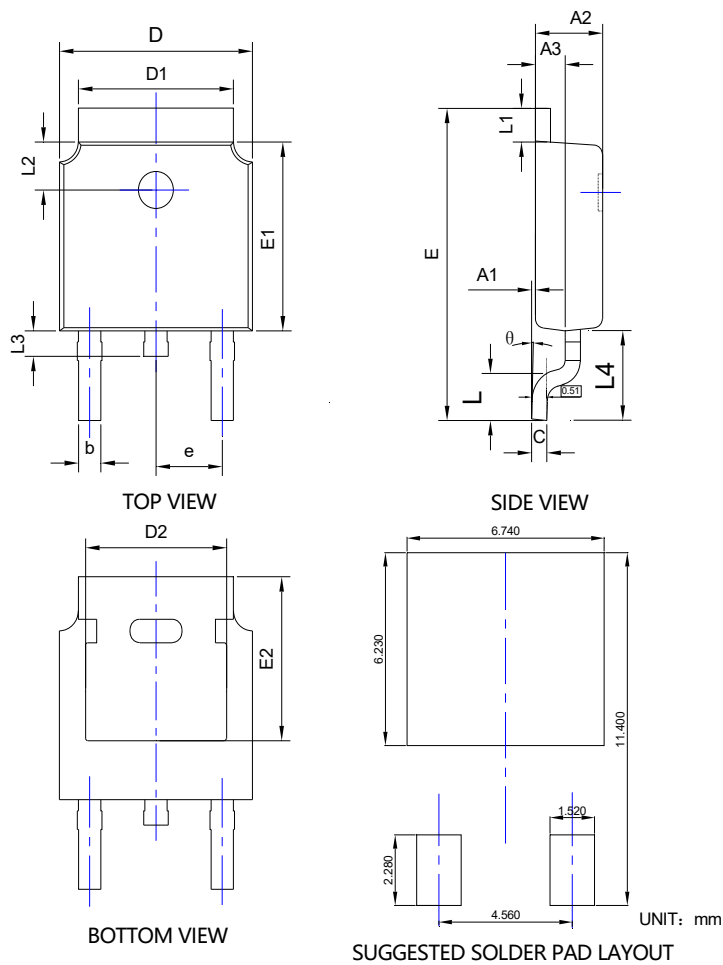


Figure 14. Safe Operation Area



YJD055P06AHQ

■ TO-252-B Package Information



SYMBOL	DIMENSIONS					
	INCHES			Millimeter		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A1	0.000	---	0.008	0.000	---	0.200
A2	0.087	0.091	0.094	2.200	2.300	2.400
A3	0.035	0.039	0.043	0.900	1.000	1.100
b	0.026	0.030	0.034	0.660	0.760	0.860
c	0.018	0.020	0.023	0.460	0.520	0.580
D	0.256	0.260	0.264	6.500	6.600	6.700
D1	0.203	0.209	0.215	5.150	5.300	5.450
D2	0.181	0.189	0.195	4.600	4.800	4.950
E	0.390	0.398	0.406	9.900	10.100	10.300
E1	0.236	0.240	0.244	6.000	6.100	6.200
E2	0.203	0.209	0.215	5.150	5.300	5.450
e	0.090BSC			2.286BSC		
L	0.049	0.059	0.069	1.250	1.500	1.750
L1	0.035	---	0.050	0.900	---	1.270
L2	0.055	---	0.075	1.400	---	1.900
L3	0.024	0.031	0.039	0.600	0.800	1.000
L4	0.114REF			2.900REF		
θ	0°	---	10°	0°	---	10°

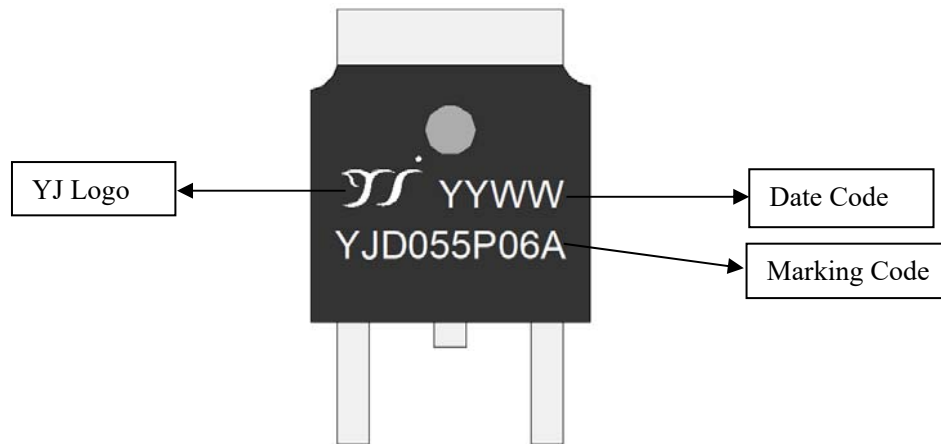
NOTE:

1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
2. TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
3. THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.



YJD055P06AHQ

■ Marking Information



Note:

1. All marking is at middle of the product body
2. All marking is in laser printing
3. YJD055P06A is Marking Code, YYWW is date code, "YY" is year, "WW" is week
4. Body color: Black



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